## **AMENDMENTS TO THE CLAIMS:**

This listing of claims will replace all prior versions and listings of claims in the abovereferenced application.

## **Listing of Claims:**

- 1.-39 Canceled.
- 40. (currently amended) A method of producing an oriented oxide superconducting film, comprising:
  - (a) providing a metal oxyfluoride film on a substrate, said metal oxyfluoride film comprising the constituent metallic elements of an oxide superconductor in substantially stoichiometric proportions;
  - (b) converting the metal oxyfluoride into the oxide superconductor in a processing gas having a total pressure less than atmospheric pressure <u>under conditions that</u> enable the removal of HF from the film surface.
- 41. (original) The method of claim 40, wherein the total pressure is less than about 8 Torr.
- 42. (original) The method of claim 41, wherein the total pressure is less than about 1 Torr.
- 43. (original) The method of claim 42, wherein the total pressure is less than about 0.1 Torr.
- 44. (original) The method of claim 43, wherein the total pressure is less than about 0.01 Torr.
- 45. (original) The method of claim 44, wherein the total pressure is less than about 0.01 Torr.
- 46. (original) The method of claim 45, wherein the total pressure is less than about 0.001 Torr.
- 47. (original) The method of claim 40, wherein the processing gas consists substantially of water vapor and oxygen.
- 48. (currently amended) The method of claim 40, further comprising depositing a buffer layer on the substrate before step (a) the step of depositing.

- 49. (original) The method of claim 48, wherein the buffer layer comprises a member of yttria-stabilized zirconia, LaAlO<sub>3</sub>, SrTiO<sub>3</sub>, CeO<sub>2</sub>, Y<sub>2</sub>O<sub>3</sub>, and MgO and any combination of the above.
- 50. (original) The method of claim 40, wherein the film has a thickness of at least 0.3μm.
- 51. (original) The method of claim 50, wherein the film has a thickness of at least 0.5mm.
- 52. (original) The method of claim 51, wherein the film has a thickness of at least 0.8 μm.
- 53. (original) The method of claim 52, wherein the film has a thickness of at least 1 μm.
- 54. (original) The method of claim 40, wherein the superconductor comprises YBCO.
- 55. (original) The method of claim 40, wherein the substrate comprises a ceramic.
- 56. (original) The method of claim 55, wherein the ceramic is selected from the group consisting of YSZ, LaAlO3, SrTiO3, CeO2, and MgO.
- 57. (original) The method of claim 40, wherein the substrate comprises a metal having a texture selected from untextured, uniaxial texturing, and biaxial texturing.
- 58. (original) The method of claim 57, wherein the metal is selected from steel, nickel, iron, molybdenum, copper, silver, and alloys and mixtures thereof.
- 59. (original) The method of claim 40, wherein the film has a Jc greater than 0.45 MA/cm2.
- 60. (original) The method of claim 59, wherein the film has a Jc greater than 1 MA/cm2.
- 61. (original) The method of claim 60, wherein the film has a Jc greater than 2 MA/cm2.
- 62. (original) The method of claim 61, wherein the film has a Jc greater than 4 MA/cm2.

- 63. (new claim) A c-axis textured superconducting film fabricated by the steps of
  - (a) providing a metal oxyfluoride film on a substrate, said metal oxyfluoride film comprising the constituent metallic elements of an oxide superconductor in substantially stoichiometric proportions; and
  - (b) converting the metal oxyfluoride into the oxide superconductor in a processing gas having a total pressure less than atmospheric pressure under conditions that enable the removal of HF from the film surface.
- 64. (new claim) The c-axis textured superconducting film of claim 63, wherein the texture is biaxial.
- 65. (new claim) The c-axis textured superconducting film of claim 63, wherein the film has a Jc greater than 0.45 MA/cm<sup>2</sup>.
- 66. (new claim) The c-axis textured superconducting film of claim 65, wherein the film has a Jc greater than 1 MA/cm<sup>2</sup>.
- 67. (new claim) The c-axis textured superconducting film of claim 66, wherein the film has a Jc greater than 2 MA/cm<sup>2</sup>.
- 68. (new claim) The c-axis textured superconducting film of claim 67, wherein the film has a Jc greater than 4 MA/cm<sup>2</sup>.
- 69. (new claim) The c-axis textured superconducting film of claim 63, wherein the total pressure is less than about 8 Torr.
- 70. (new claim) The c-axis textured superconducting film of claim 63, wherein the total pressure is less than about 1 Torr.
- 71. (new claim) The c-axis textured superconducting film of claim 70, wherein the total pressure is less than about 0.1 Torr.
- 72. (new claim) The c-axis textured superconducting film of claim 71, wherein the total pressure is less than about 0.01 Torr.

- 73. (new claim) The c-axis textured superconducting film of claim 72, wherein the total pressure is less than about 0.01 Torr.
- 74. (new claim) The c-axis textured superconducting film of claim 73, wherein the total pressure is less than about 0.001 Torr.
- 75. (new claim) The c-axis textured superconducting film of claim 63, wherein the processing gas consists substantially of water vapor and oxygen.
- 76. (new claim) The c-axis textured superconducting film of claim 63, wherein the substrate comprises a base and a buffer layer interposed between the base and the superconducting film.
- 77. (new claim) The c-axis textured superconducting film of claim 76, wherein the buffer layer comprises a member of ceria, yttria-stabilized zirconia, yttrium oxide, and any combination of the above.
- 78. (new claim) The c-axis textured superconducting film of claim 63, wherein the film has a thickness of at least 0.5 µm.
- 79. (new claim) The c-axis textured superconducting film of claim 78, wherein the film has a thickness of at least 1 µm.
- 80. (new claim) The c-axis textured superconducting film of claim 63, wherein the superconductor comprises YBCO.
- 81. (new claim) The c-axis textured superconducting film of claim 63, wherein the substrate comprises a ceramic.
- 82. (new claim) The c-axis textured superconducting film of claim 81, wherein the ceramic is selected from the group consisting of YSZ, LaAlO<sub>3</sub>, SrTiO<sub>3</sub>, CeO<sub>2</sub>, and MgO.
- 83. (new claim) The c-axis textured superconducting film of claim 63, wherein the substrate comprises a metal.
- 84. (new claim) The c-axis textured superconducting film of claim 83, wherein the metal is selected from steel, nickel, iron, molybdenum, copper, silver, and alloys and mixtures thereof.